

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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Infrared Light Emitting Diode

OPR2800T



Features:

- High-power GaAlAs
- Matches PLCC-2 footprint
- 875 nm wavelength
- Wide beam angle
- Wide operating temperature range (-40° C to +100° C)



Description:

The **OPR2800T** is a GaAlAs infrared LED mounted in a surface mount chip carrier (SMCC) package with a flat lens window that allows a wide beam angle. The SMCC format has a lower height profile than the PLCC-2 package and mounts in the same footprint. The device is suitable for use in single device or array applications. The OPR2800T is spectrally matched to the OPR5500 phototransistor.

See Application Bulletin 237 for handling instructions.

Applications:

• Non-contact position sensing

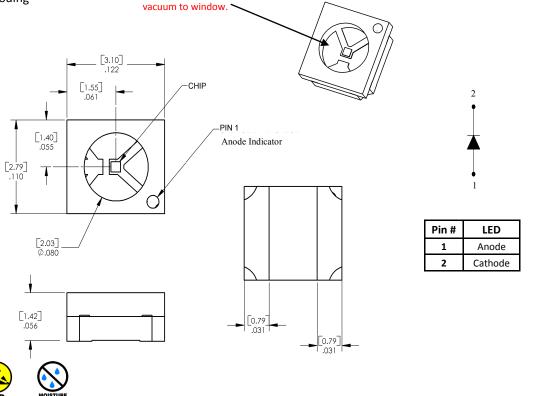
• Datum detection

• Machine automation

• Optical encoding

Warning: Front Window is pressure sensitive. Do not apply pressure or high

Ordering Information							
Part	LED Peak	Total					
Number	Wavelength	Beam Angle	Packaging				
OPR2800T	875 nm	100°	Tape & Reel				





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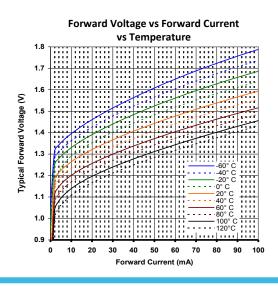
Absolute Maximum Ratings (T _A = 25° C unless otherwise noted)				
Storage Temperature Range	-55° C to +125° C			
Operating Temperature Range	-40° C to +100° C			
Reverse Voltage	30 V			
Continuous Forward Current	50 mA			
Solder reflow time within 5°C of peak temperature is 20 to 40 seconds ⁽¹⁾	250° C			
Power Dissipation	130 mW ⁽²⁾			

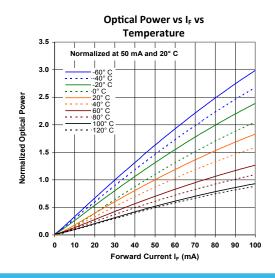
Electrical Characteristics (T _A = 25° C unless otherwise noted)							
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS	
E _{e (APT)}	Apertured Radiant Incidence	0.2	-	-	mW/ cm²	I _F = 20 mA ⁽³⁾	
V _F	Forward Voltage	-	-	1.50	V	I _F = 50 mA	
I _R	Reverse Current	-	-	100	μΑ	V _R = 2.0 V	
$\lambda_{\scriptscriptstyle P}$	Wavelength at Peak Emission		875	-	nm	I _F = 10 mA	
θ_{HP}	Emission Angle at Half Power Points	-	100	-	Degree	I _F = 20 mA	
t _r , t _f	Output Rise Time, Output Fall Time	-	-	500	ns	I _{F(PK)} = 100 mA, PW = 10 μs, D.C. = 10.0%	

Notes

- 1. Solder time less than 5 seconds at temperature extreme.
- 2. Derate linearly at 1.39 mW/° C above 25° C.
- 3. E_{e(APT)} is a measurement of the apertured radiant incidence upon a sensing area 0.081" (2.06 mm) in diameter, perpendicular to and centered on the mechanical axis of the lens and 0.590" (14.99 mm) from the measurement surface. EE_(APT) is not necessarily uniform within the measured area.

OPR2800T





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